

BAT54W1 SCHOTTKY BARRIER DIODE

Features

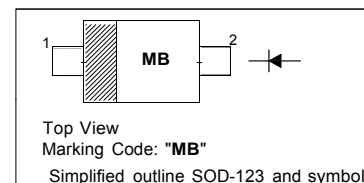
- Low forward voltage

Applications

- Ultra high-speed switching
- Voltage clamping
- Protection circuits

PINNING

| PIN | DESCRIPTION |
|-----|-------------|
| 1 | Cathode |
| 2 | Anode |



Absolute Maximum Ratings ($T_a = 25\text{ }^\circ\text{C}$)

| Parameter | Symbol | Value | Unit |
|---|------------|---------------|--------------------|
| Reverse Voltage | V_R | 30 | V |
| Forward Current | I_F | 200 | mA |
| Repetitive Peak Forward Current | I_{FRM} | 300 | mA |
| Peak Forward Surge Current ($t_p = 10\text{ ms}$) | I_{FSM} | 600 | mA |
| Power Dissipation | P_D | 230 | mW |
| Thermal Resistance from Junction Ambient | R_{thJA} | 435 | $^\circ\text{C/W}$ |
| Junction Temperature | T_J | 125 | $^\circ\text{C}$ |
| Storage Temperature Range | T_{stg} | - 65 to + 150 | $^\circ\text{C}$ |

Characteristics at $T_a = 25\text{ }^\circ\text{C}$

| Parameter | Symbol | Max. | Unit |
|---|----------|---------------------------------|---------------|
| Forward Voltage at $I_F = 0.1\text{ mA}$ at $I_F = 1\text{ mA}$ at $I_F = 10\text{ mA}$ at $I_F = 30\text{ mA}$ at $I_F = 100\text{ mA}$ | V_F | 240 320 400 500 800 | mV |
| Reverse Current at $V_R = 25\text{ V}$ | I_R | 2 | μA |
| Total Capacitance at $V_R = 1\text{ V}$, $f = 1\text{ MHz}$ | C_T | 10 | pF |
| Reverse Recovery Time at $I_F = 10\text{ mA}$, $V_R = 6\text{ V}$, $I_R = 10\text{ mA}$, $R_L = 100\ \Omega$ | t_{rr} | 6 | ns |

FIG.1 – ADMISSIBLE POWER DISSIPATION VS. AMBIENT TEMPERATURE

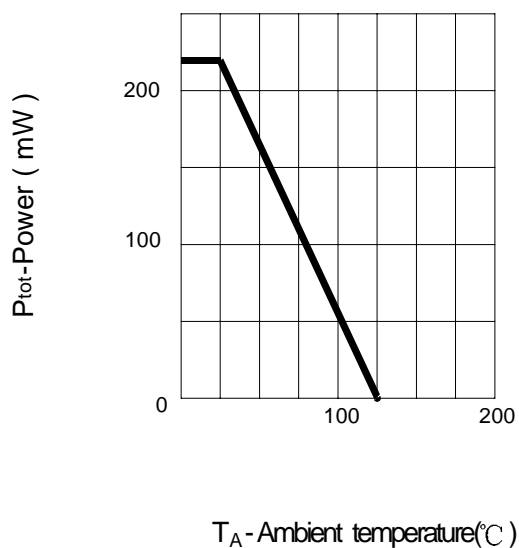


FIG. 2 – TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

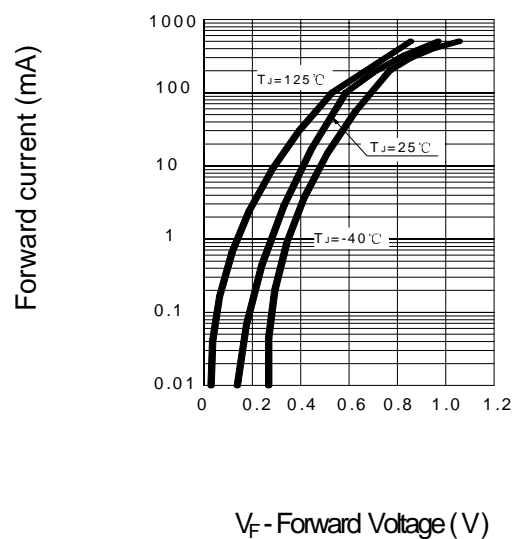


FIG. 3 – TYPICAL REVERSE CHARACTERISTICS

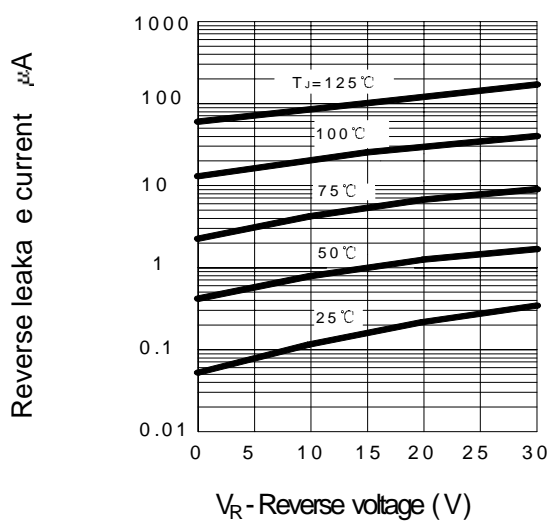
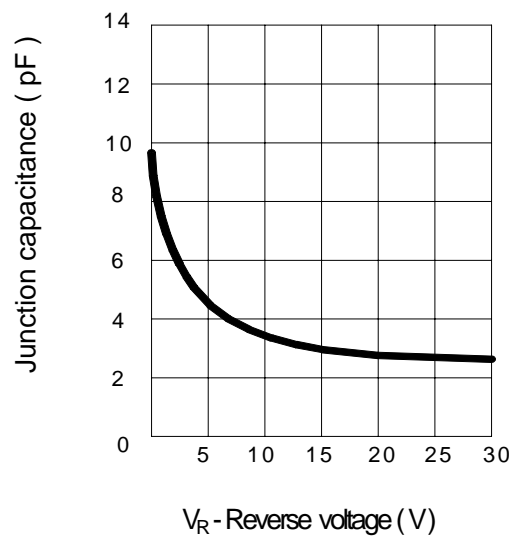


FIG.4 – TYPICAL JUNCTION CAPACITANCE



PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SOD-123

